DISCRETE SEMICONDUCTORS



Preliminary specification File under Discrete Semiconductors, SC09 1996 May 21



BGY152A; BGY152B

FEATURES

- 7.2 V nominal supply voltage
- 7 W output power
- Easy output power control by DC voltage.

APPLICATIONS

• Portable communication equipment operating in the 400 to 470 MHz and 450 to 512 MHz frequency ranges respectively.

DESCRIPTION

The BGY152A and BGY152B are four-stage power amplifier modules in a SOT434A package. Each module consists of three MOSFET's and one bipolar transistor chip mounted together with matching and bias circuit components on a metallized ceramic substrate. These modules produce an output power of 7 W into a load of 50 Ω at a supply voltage of 7.2 V with an RF drive power of 1 mW.

QUICK REFERENCE DATA

RF performance at T_{mb} = 25 °C.

ТҮРЕ	MODE OF OPERATION	f (MHz)	V _S (V)	P _L (W)	G _p (dB)	η (%)	Z _S ; Z _L (Ω)
BGY152A	CW	400 to 470	7.2	7	≥38.5	≥40	50
BGY152B	CW	450 to 512	7.2	7	≥38.5	≥40	50

PINNING - SOT434A

PIN	DESCRIPTION		
1	RF input + V _C		
2	V _{S1}		
3	V _{S2}		
4	V _{S3}		
5	RF output		
Flange	ground		



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _{S1}	DC supply voltage	_	9	V
V _{S2}	DC supply voltage		9	V
V _{S3}	DC supply voltage	-	9	V
V _C	DC control voltage	_	7.5	V
PD	input drive power	-	5	mW
PL	load power	_	9	W
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-30	+100	°C

CHARACTERISTICS

 $Z_S = Z_L = 50 \ \Omega; \ P_D = 1 \ mW; \ V_{S1} = V_{S2} = V_{S3} = 7.2 \ V; \ V_C \leq 7.2 \ V; \ T_{mb} = 25 \ ^\circ C; \ unless \ otherwise \ specified.$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency					
	BGY152A		400	-	470	MHz
	BGY152B		450	-	512	MHz
I _{Q1} +I _{Q2} +I _{Q3}	total leakage current	$V_{\rm C} = 0; P_{\rm D} = 0$	-	-	200	μA
PL	load power		7	-	-	W
G _p	power gain	adjust V_C for $P_L = 7 W$	38.5	-	-	dB
η	efficiency	adjust V_C for $P_L = 7 W$	40	43	-	%
H ₂	second harmonic	adjust V_C for $P_L = 7 W$	-	-	-35	dBc
H ₃	third harmonic	adjust V_C for $P_L = 7 W$	-	-	-40	dBc
VSWR _{in}	input VSWR	adjust V_C for $P_L = 7 W$	-	-	2:1	
	control range	$V_{\rm C} = 0$ to 7.2 V; $P_{\rm D} = 1$ mW	70	-	-	dB
	stability	$\begin{array}{l} P_D = 0.5 \text{ to } 2 \text{ mW}; \text{ V}_S = 6 \text{ to } 9 \text{ V};\\ \text{adjust } V_C \text{ for } P_L \leq 9 \text{ W};\\ \text{VSWR} \leq 8 : 1 \text{ through all phases} \end{array}$	-	-	-60	dBc
	ruggedness	$V_S = 9 V$; adjust V_C for $P_L \le 9 W$ VSWR ≤ 20 : 1 through all phases	nc	no degradation		

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PACKAGE OUTLINE



BGY152A; BGY152B

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
more of the limiting values of the device at these or at	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.
Application information	
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LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.